Errata

Erratum: Variational principles for solving nonlinear Poisson equations for the potential of impurity ions in semiconductors with spatially variable dielectric constants [Phys. Rev. B 17, 3177 (1978)]

P. Csavinszky

In this paper there are two printing errors. Equations (19a) and (19b) appeared without their right-hand sides. The correct equations are

$$\phi(r \to 0) = e_0/r\,, \tag{19a}$$

$$\phi(r \to \infty) = 0\,. \tag{19b}$$

Erratum: Self-consistent calculations of interface states and electronic structure of the (110) interfaces of Ge-GaAs and AlAs-GaAs [Phys. Rev. B 17, 815 (1978)]

Warren E. Pickett, Steven G. Louie, and Marvin L. Cohen

In the first full paragraph on p. 820, the Ge-Ga and Ge-As interface bond charges should be changed, from 1.89 and 2.11, to 1.77 and 2.23, respectively. This correction changes only the following sentence: The bond charges at the interface are *not* significantly more uniform than simple chemical considerations would indicate. In Sec. IV B the number 2.11 should also be changed to 2.23.

We thank J. Ihm for pointing out a coding error which resulted in the deviation in bond charge from 2.00 being too small by a factor of 2.

Erratum: Crystal-field effects on the transport properties of rare-earth intermetallics [Phys. Rev. B 17, 3899 (1978)]

Y. H. Wong

Equation (2) should read

$$\frac{\kappa(T)}{\kappa_{\mathrm{metal}}} = \cdots\,.$$

Equation (3) should read

$$F(\omega, T) = \left(1 + V_0^{-2} \sum_{\alpha\beta} \cdots\right)^{-1}.$$

Equation (6) should read

$$F(\omega, T) = [1 + \cdots]^{-1}\,.$$